## V60DM120C-M3, V60DM120CHM3

Vishay General Semiconductor

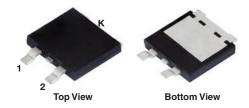
**HALOGEN** 

FREE

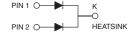
# **Dual High-Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.43 \text{ V}$  at  $I_F = 5 \text{ A}$ 

### TMBS<sup>®</sup> eSMP<sup>®</sup> Series TO-263AC (SMPD)



#### V60DM120C



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 30 A			
$V_{RRM}$	120 V			
I <sub>FSM</sub>	320 A			
V <sub>F</sub> at I <sub>F</sub> = 30 A (T <sub>A</sub> = 125 °C)	0.70 V			
T <sub>J</sub> max.	175 °C			
Package	TO-263AC (SMPD)			
Diode variations	Dual common cathode			

### **FEATURES**

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- · High efficiency operation
- AEC-Q101 qualified available:
  - Automotive ordering code: base P/NHM3
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

### **TYPICAL APPLICATIONS**

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, inductrial, and automotive application.

### **MECHANICAL DATA**

Case: TO-263AC (SMPD)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V60DM120C	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	120	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub>	60	^	
	per diode		30	А	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	320	А	
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to +175	°C	

# V60DM120C-M3, V60DM120CHM3

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.51	-	. v	
	I <sub>F</sub> = 15 A			0.68	-		
	I <sub>F</sub> = 30 A			0.87	0.97		
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.43	-		
	I <sub>F</sub> = 15 A			0.58	-		
	I <sub>F</sub> = 30 A			0.69	0.77		
Reverse current at rated V <sub>R</sub> per diode	V <sub>R</sub> = 90 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	0.01	-	mA	
		T <sub>A</sub> = 125 °C		5	-		
	V <sub>R</sub> = 120 V	T <sub>A</sub> = 25 °C		-	0.7		
		T <sub>A</sub> = 125 °C		10	35		

#### Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V60DM120C	UNIT	
Typical thermal resistance	per device	$R_{ heta JC}$	0.95	°C/W	
	per device	R <sub>0JA</sub> (1)(2)	45		

#### Notes

 $^{(1)}$  The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

(2) Free air, without heatsink

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V60DM120C-M3/I	0.55	1	2000/reel	13" diameter plastic tape and reel		
V60DM120CHM3/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel		

### Note

(1) AEC-Q101 qualified

### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

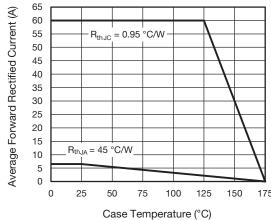


Fig. 1 - Forward Current Derating Curve

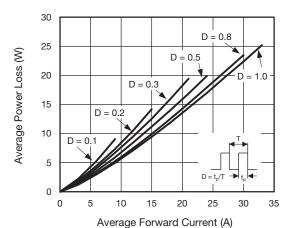


Fig. 2 - Forward Power Loss Characteristics Per Diode





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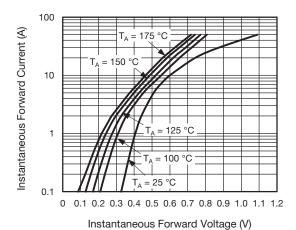


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

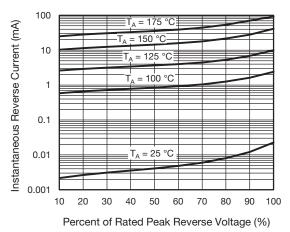


Fig. 4 - Typical Reverse Characteristics Per Diode

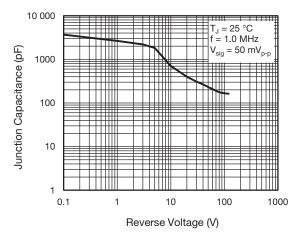


Fig. 5 - Typical Junction Capacitance Per Diode

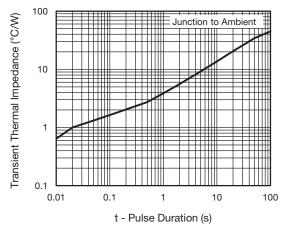


Fig. 6 - Typical Transient Thermal Impedance Per Device

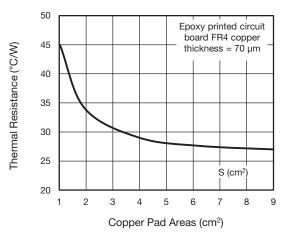
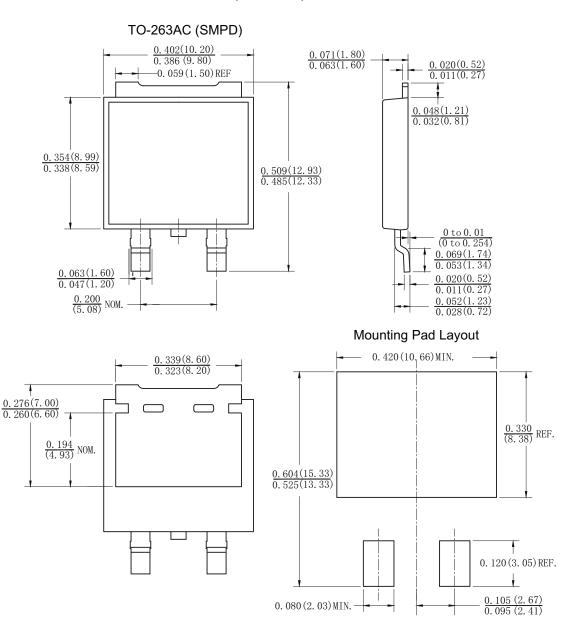


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas



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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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